

IR21531(D)(S)&(PbF)

SELF-OSCILLATING HALF-BRIDGE DRIVER

Features

- Integrated 600V half-bridge gate driver
- 15.6V zener clamp on V_{CC}
- True micropower start up
- Tighter initial deadtime control
- Low temperature coefficient deadtime
- Shutdown feature (1/6th V_{CC}) on C_T pin
- Increased undervoltage lockout Hysteresis (1V)
- Lower power level-shifting circuit
- Constant LO, HO pulse widths at startup
- Lower di/dt gate driver for better noise immunity
- Low side output in phase with R_T
- Internal 50nsec (typ.) bootstrap diode (IR21531D)
- Excellent latch immunity on all inputs and outputs
- ESD protection on all leads
- Also available LEAD-FREE

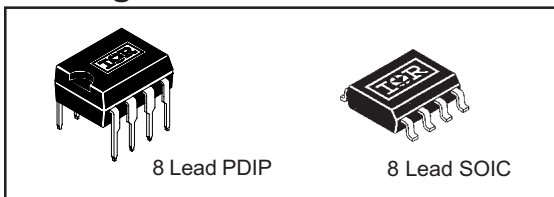
Description

The IR21531(D)(S) are an improved version of the popular IR2155 and IR2151 gate driver ICs, and incorporate a high voltage half-bridge gate driver with a front end oscillator similar to the industry standard CMOS 555 timer. The IR21531 provides more functionality and is easier to use than previous ICs. A shutdown feature has been designed into the C_T pin, so that both gate driver outputs can be disabled using a low voltage control signal. In addition, the gate driver output pulse widths are the same once the rising undervoltage lockout threshold on V_{CC} has been reached, resulting in a more stable profile of frequency vs time at startup. Noise immunity has been improved significantly, both by lowering the peak di/dt of the gate drivers, and by increasing the undervoltage lockout hysteresis to 1V. Finally, special attention has been paid to maximizing the latch immunity of the device, and providing comprehensive ESD protection on all pins.

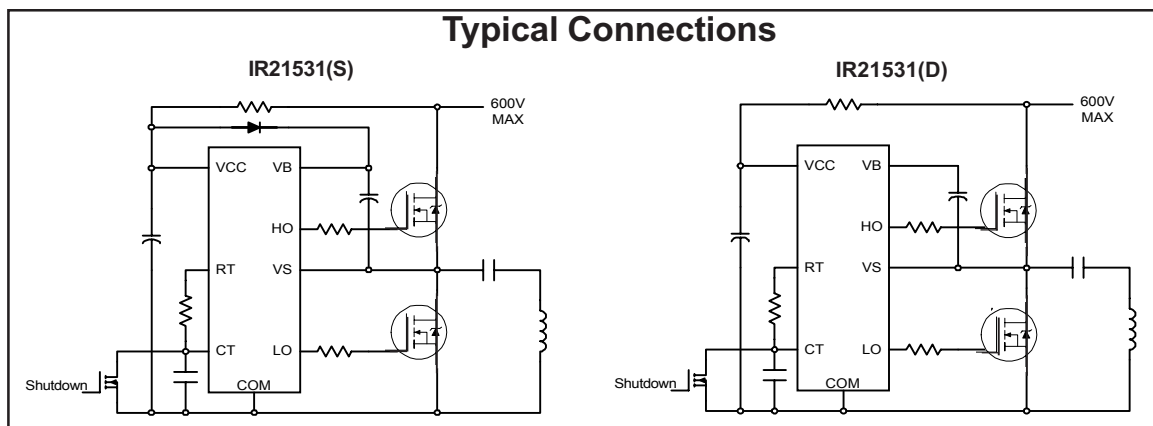
Product Summary

V _{OFFSET}	600V max.
Duty Cycle	50%
T _r /T _p	80/40ns
V _{clamp}	15.6V
Deadtime (typ.)	0.6 μs

Packages



Typical Connections



IR21531(D)(S)&(PbF)

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Absolute Maximum Ratings

Absolute maximum ratings indicate sustained limits beyond which damage to the device may occur. All voltage parameters are absolute voltages referenced to COM, all currents are defined positive into any lead. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

Symbol	Definition	Min.	Max.	Units
V_B	High side floating supply voltage	-0.3	625	V
V_S	High side floating supply offset voltage	$V_B - 25$	$V_B + 0.3$	
V_{HO}	High side floating output voltage	$V_S - 0.3$	$V_B + 0.3$	
V_{LO}	Low side output voltage	-0.3	$V_{CC} + 0.3$	
V_{RT}	R_T pin voltage	-0.3	$V_{CC} + 0.3$	
V_{CT}	C_T pin voltage	-0.3	$V_{CC} + 0.3$	
I_{CC}	Supply current (note 1)	—	25	mA
I_{RT}	R_T pin current	-5	5	
dV_S/dt	Allowable offset voltage slew rate	-50	50	V/ns
P_D	Maximum power dissipation @ $T_A \leq +25^\circ\text{C}$ (8 Lead DIP)	—	1.0	W
	(8 Lead SOIC)	—	0.625	
R_{thJA}	Thermal resistance, junction to ambient (8 Lead DIP)	—	125	$^\circ\text{C/W}$
	(8 Lead SOIC)	—	200	
T_J	Junction temperature	-55	150	$^\circ\text{C}$
T_S	Storage temperature	-55	150	
T_L	Lead temperature (soldering, 10 seconds)	—	300	

Recommended Operating Conditions

For proper operation the device should be used within the recommended conditions.

Symbol	Definition	Min.	Max.	Units
V_{BS}	High side floating supply voltage	$V_{CC} - 0.7$	V_{CLAMP}	V
V_S	Steady state high side floating supply offset voltage	-3.0 (note 2)	600	
V_{CC}	Supply voltage	10	V_{CLAMP}	
I_{CC}	Supply current	(note 3)	5	mA
T_J	Junction temperature	-40	125	$^\circ\text{C}$

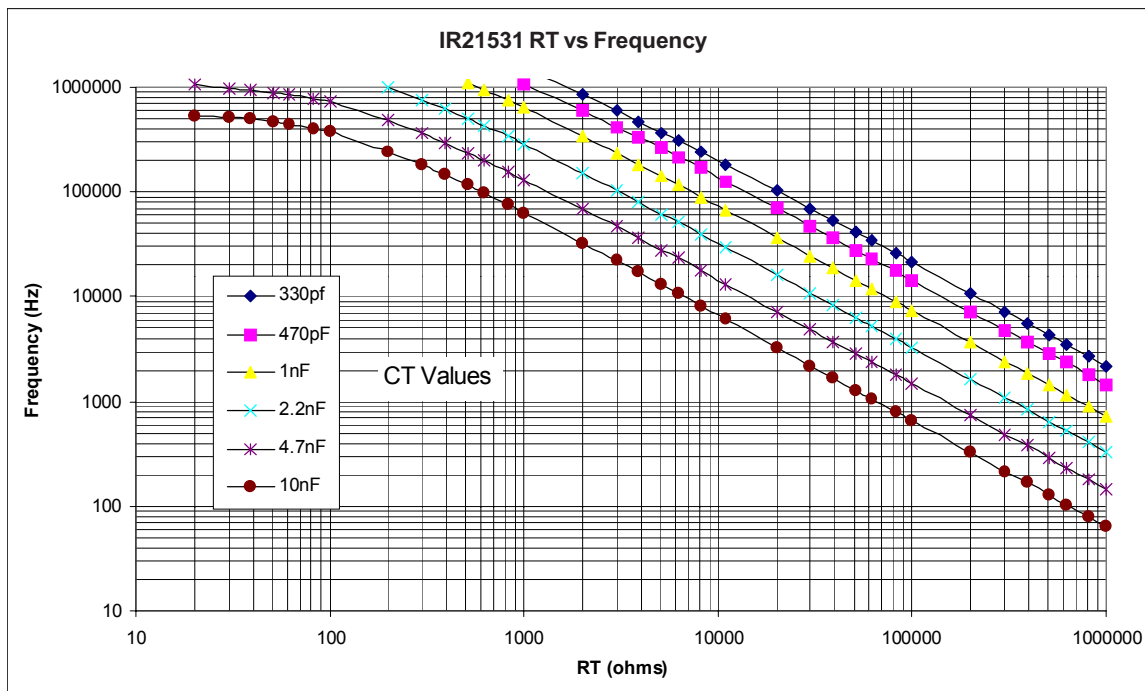
Note 1: This IC contains a zener clamp structure between the chip V_{CC} and COM which has a nominal breakdown voltage of 15.6V. Please note that this supply pin should not be driven by a DC, low impedance power source greater than the V_{CLAMP} specified in the Electrical Characteristics section.

Note 2: Care should be taken to avoid output switching conditions where the V_S node flies inductively below ground by more than 5V.

Note 3: Enough current should be supplied to the V_{CC} pin of the IC to keep the internal 15.6V zener diode clamping the voltage at this pin.

Recommended Component Values

Symbol	Component	Min.	Max.	Units
R_T	Timing resistor value	10	—	$k\Omega$
C_T	C_T pin capacitor value	330	—	pF



IR21531(D)(S)&(PbF)

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Electrical Characteristics

V_{BIAS} (V_{CC}, V_{BS}) = 12V, C_L = 1000 pF, C_T = 1 nF and T_A = 25°C unless otherwise specified. The V_{IN}, V_{TH} and I_{IN} parameters are referenced to COM. The V_O and I_O parameters are referenced to COM and are applicable to the respective output leads: HO or LO.

Low Voltage Supply Characteristics						
Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
V _{CCUV+}	Rising V _{CC} undervoltage lockout threshold	8.1	9.0	9.9	V	
V _{CCUV-}	Falling V _{CC} undervoltage lockout threshold	7.2	8.0	8.8		
V _{CCUVH}	V _{CC} undervoltage lockout Hysteresis	0.5	1.0	1.5		
I _{QCCUV}	Micropower startup V _{CC} supply current	—	75	150	μA	V _{CC} ≤ V _{CCUV-}
I _{QCC}	Quiescent V _{CC} supply current	—	500	950		
V _{CLAMP}	V _{CC} zener clamp voltage	14.4	15.6	16.8	V	I _{CC} = 5mA
Floating Supply Characteristics						
Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
I _{QBSUV}	Micropower startup V _{BS} supply current	—	0	10	μA	V _{CC} ≤ V _{CCUV-}
I _{QBS}	Quiescent V _{BS} supply current	—	30	50		
V _{BSMIN}	Minimum required V _{BS} voltage for proper functionality from R _T to HO	—	4.0	5.0	V	V _{CC} = V _{CCUV+} + 0.1V
I _{LK}	Offset supply leakage current	—	—	50	μA	V _B = V _S = 600V
V _F	Bootstrap diode forward voltage (IR21531D)	0.5	—	1.0	V	I _F = 250mA
Oscillator I/O Characteristics						
Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
f _{osc}	Oscillator frequency	19.4	20	20.6	kHz	R _T = 36.9kΩ
		94	100	106		R _T = 7.43kΩ
d	R _T pin duty cycle	48	50	52	%	f _o < 100kHz
I _{CT}	C _T pin current	—	0.001	1.0	μA	
I _{CTUV}	UV-mode C _T pin pulldown current	0.30	0.70	1.2	mA	V _{CC} = 7V
V _{CT+}	Upper C _T ramp voltage threshold	—	8.0	—	V	
V _{CT-}	Lower C _T ramp voltage threshold	—	4.0	—		
V _{CTSD}	C _T voltage shutdown threshold	1.8	2.1	2.4		
V _{RT+}	High-level R _T output voltage, V _{CC} - V _{RT}	—	10	50	mV	I _{RT} = 100μA
		—	100	300		I _{RT} = 1mA
V _{RT-}	Low-level R _T output voltage	—	10	50		I _{RT} = 100μA
		—	100	300		I _{RT} = 1mA
V _{RTUV}	UV-mode R _T output voltage	—	0	100		V _{CC} ≤ V _{CCUV-}
V _{RTSD}	SD-Mode R _T output voltage, V _{CC} - V _{RT}	—	10	50		I _{RT} = 100μA, V _{CT} = 0V
		—	10	300		I _{RT} = 1mA, V _{CT} = 0V

Electrical Characteristics (cont.)

Gate Driver Output Characteristics						
Symbol	Definition	Min.	Typ.	Max.	Units	Test Conditions
VOH	High level output voltage, $V_{BIAS} - V_O$	—	0	100	mV	$I_O = 0A$
VOL	Low-level output voltage, V_O	—	0	100		$I_O = 0A$
VOL_UV	UV-mode output voltage, V_O	—	0	100		$I_O = 0A$ $V_{CC} \leq V_{CCUV-}$
t_r	Output rise time	—	80	150	nsec	
t_f	Output fall time	—	45	100		
t_{sd}	Shutdown propagation delay	—	660	—		
t_d	Output deadtime (HO or LO)	0.35	0.60	0.85	μsec	

Lead Definitions

Symbol	Description
V_{CC}	Logic and internal gate drive supply voltage
R_T	Oscillator timing resistor input
C_T	Oscillator timing capacitor input
COM	IC power and signal ground
LO	Low side gate driver output
V_S	High voltage floating supply return
HO	High side gate driver output
V_B	High side gate driver floating supply

Lead Assignments

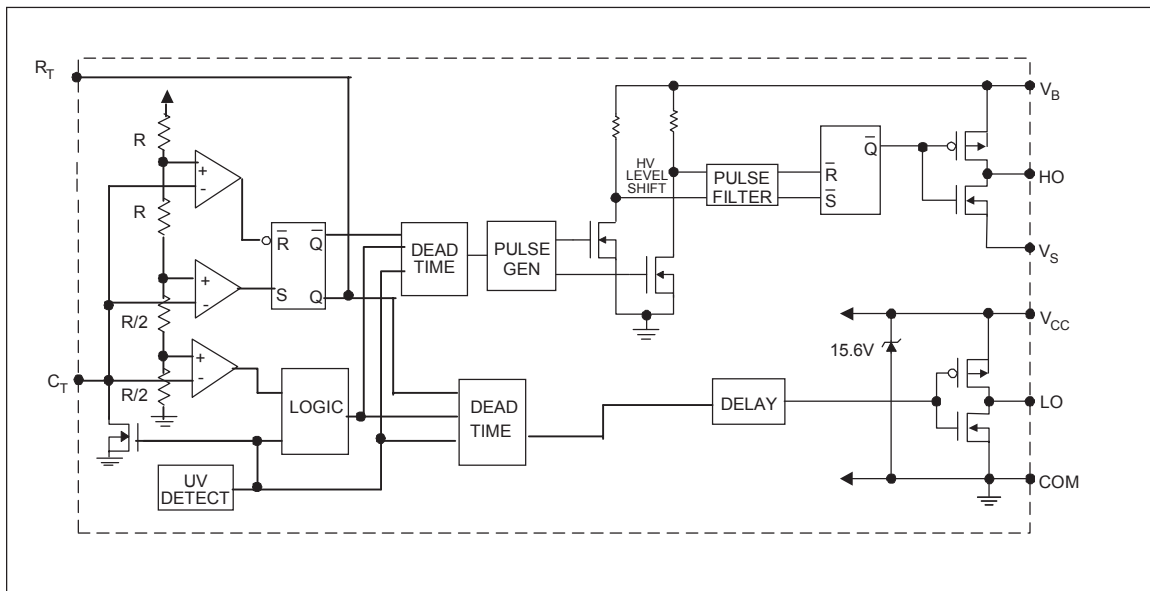
8 Lead DIP IR21531(D)	8 Lead SOIC IR21531S
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NOTE: The IR21531D is offered in 8 lead DIP only.

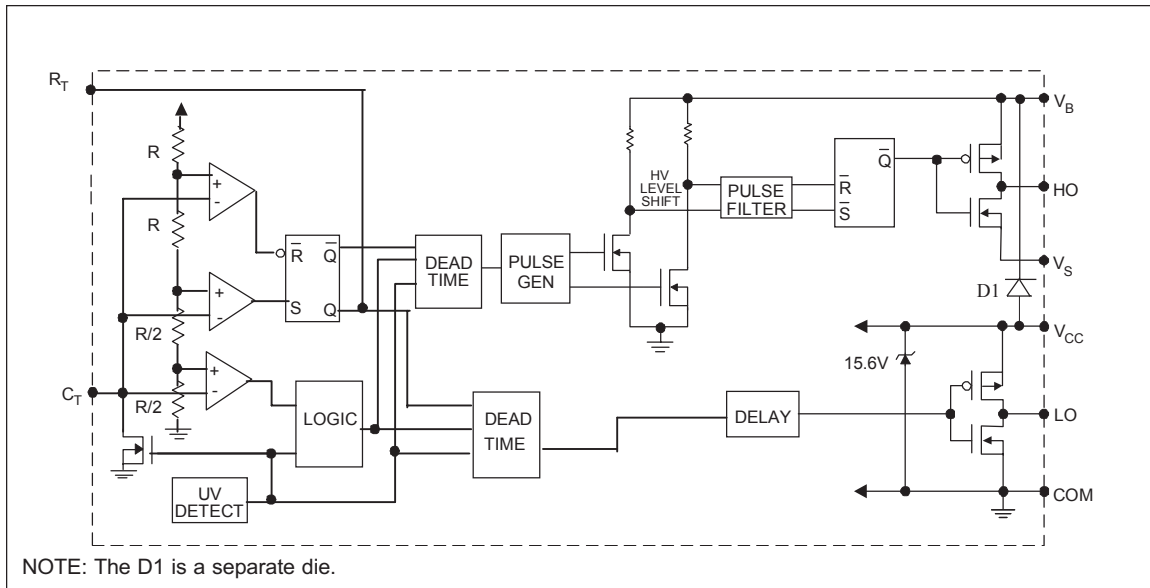
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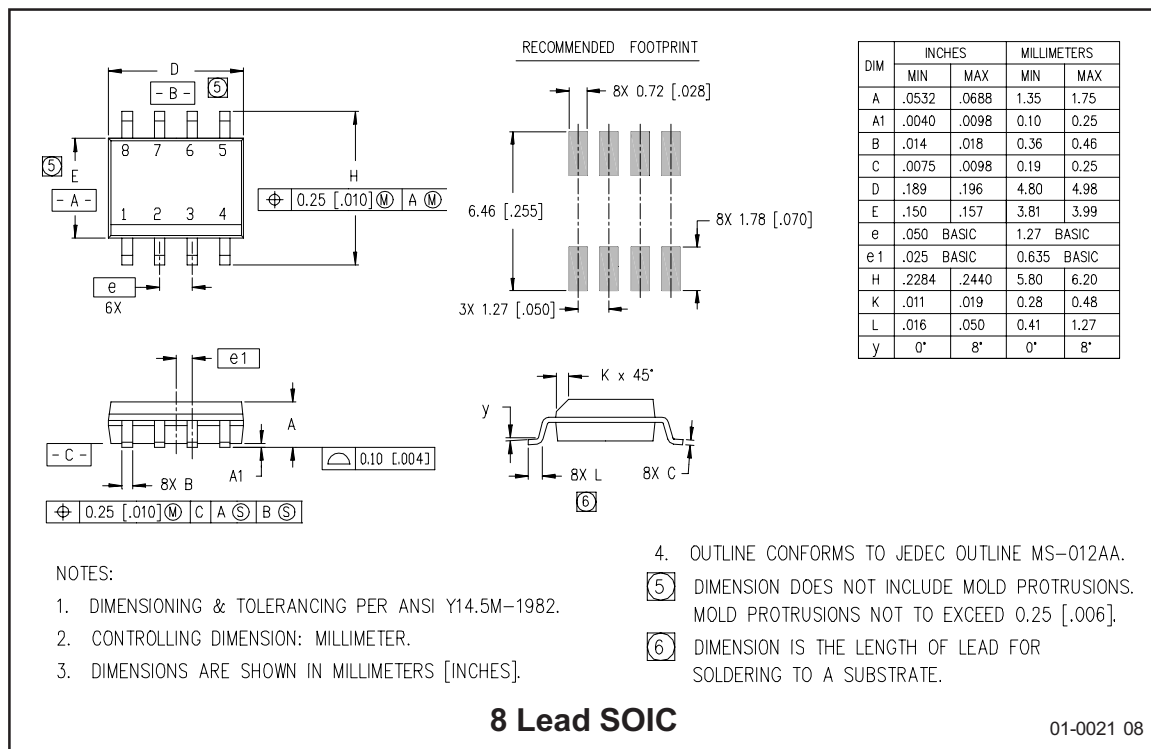
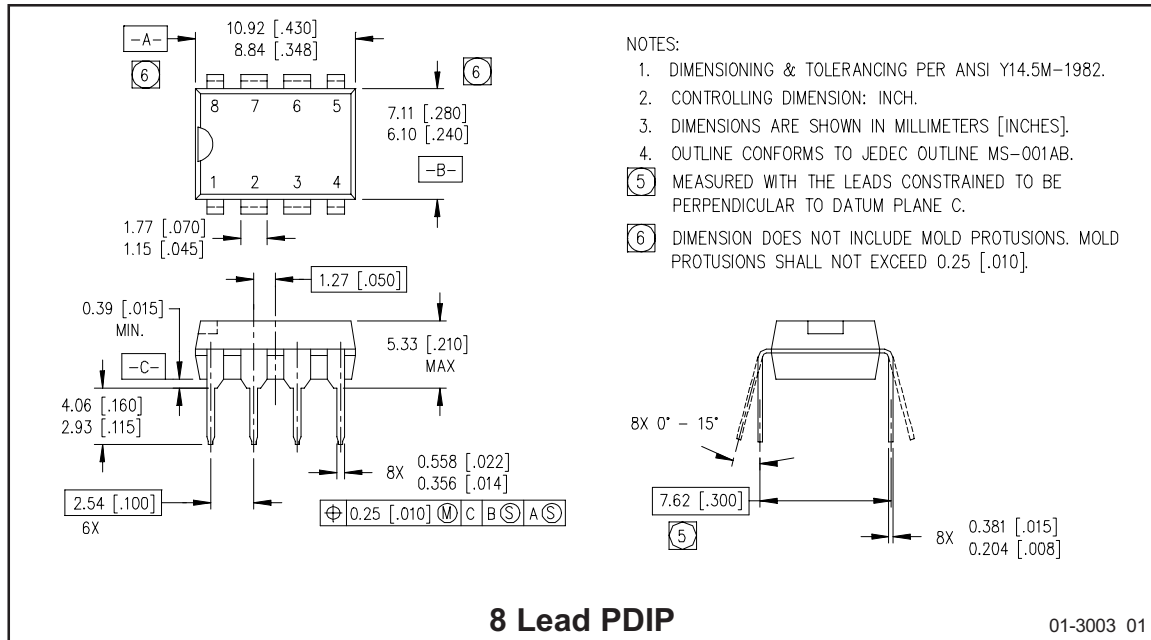
Functional Block Diagram for IR21531(S)



Functional Block Diagram for IR21531D



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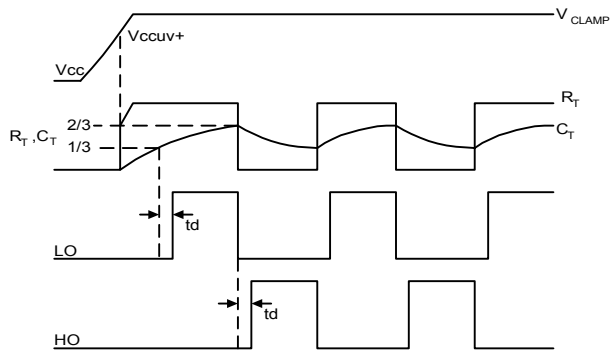


Figure 1. Input/Output Timing Diagram

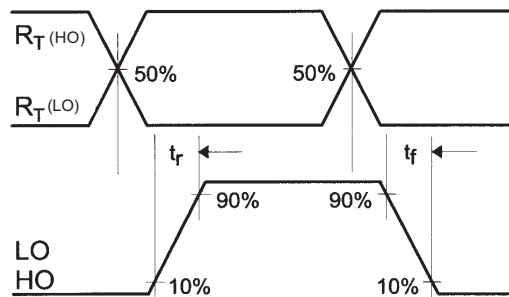


Figure 2. Switching Time Waveform Definitions

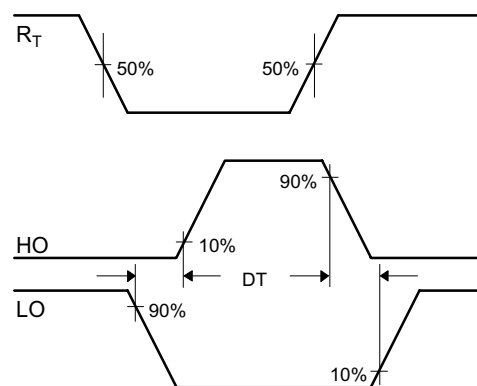
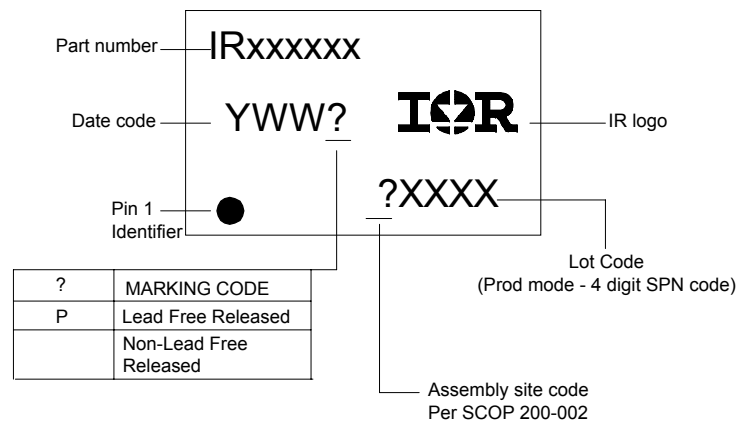


Figure 3. Deadtime Waveform Definitions

IR21531(D)(S)&(PbF)

LEADFREE PART MARKING INFORMATION



ORDER INFORMATION

Basic Part (Non-Lead Free)

8-Lead PDIP IR21531 order IR21531
8-Lead SOIC IR21531S order IR21531S
8-Lead PDIP IR21531D order IR21531D

Leadfree Part

8-Lead PDIP IR21531 order IR21531PbF
8-Lead SOIC IR21531S order IR21531SPbF
8-Lead PDIP IR21531D order IR21531DPbF